	ТУР	Hits	Search Text	DBs	Time Stamp	Comment	Error Definit ion
1	IS& R	м	(("5058800") or ("5223453") or ("5739549")).PN.	USPAT	2004/05/1 7 12:24		
2	BRS	6354	(substrate with heat\$3) and induction	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/1 3 17:31		
3	BRS	1340	((substrate with heat\$3) and induction) and electromagnetic	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/1 3 17:28		
4	BRS	113	(((substrate with heat\$3) and induction) and electromagnetic) and (specific with resistance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/1 3 17:28		
2	BRS	425	electromagnetic with heating with substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/1 3 17:32		
9	BRS	30	(electromagnetic with heating with substrate) and (specific adj resistance)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/1 4 15:02		

05/17/2004, EAST Version: 1.4.1

	Тур	Hits	Search Text	DBs	Time Stamp	Comment	Error Definit ion
7	BRS	2131	electromagnetic with heating with radiation	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/1 4 15:02		
8	BRS	22	(electromagnetic with heating with radiation) and eddy and substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/1 4 15:54		
o	BRS	т	(electromagnetic with heating with radiation) and eddy and substrate and magnet	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/1 4 15:56		
10	BRS	281	(eddy with current with heat\$3) and radiation and magnet	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/1 4 15:58	•	
11	BRS	99	((eddy with current with heat\$3) and radiation and magnet) and substrate and semiconductor	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/1 4 15:58		
12	BRS	7	438/530,540,589,661,68 0,681,684,799.ccls. and eddy	USPAT; US-PGPUB	2004/05/1 7 13:24		

05/17/2004, EAST Version: 1.4.1

TYP	Hits	Search Text	DBs	Time Stamp	Comment	Error Definit ion
BRS	3618	doping with resistance	USPAT	2004/05/1 7 13:27		
BRS	0	<pre>(doping with resistance) and (specific with resistence)</pre>	USPAT	2004/05/1 7 13:25		
BRS	0	doping near (specific with resistence)	USPAT	2004/05/1 7 13:25		
BRS	0	doping near resistence	USPAT	2004/05/1 7 13:26		
BRS	3	doping same resistence	USPAT	2004/05/1 7 13:26		
BRS	1697	(doping with resistance) and impurity	USPAT	2004/05/1 7 13:50		
BRS	47294	source with resistance	USPAT	2004/05/1 7 13:51		
BRS	15439	impurity same resistance	USPAT	2004/05/1 7 13:51		
BRS	2655	<pre>impurity with concentration with resistance</pre>	USPAT	2004/05/1 7 13:54		
BRS	587	(impurity with concentration with resistance) and capacitor	USPAT	2004/05/1 7 13:57		

	TYP e	Hits	Search Text	DBs	Time Stamp	Comment	Error Definit ion
	23 BRS 393	393	(specific with resistance) with impurity	USPAT	2004/05/1 7 13:59		
-	24 BRS 324	324	((specific with resistance) with impurity) and semiconductor	USPAT	2004/05/1 7 13:59		